Enrollment No. F.N. 21 CJ30 U 039

Branch/Specialisation: CS/EC/IT/

Computes Science



Faculty of Engineering / Science End Sem (Odd) Examination Dec-2022 CS3CO29 / CS3CO33 / EC3CO07 / IT3CO26 / BC3CO38 Digital Electronics

Durat	ion: 3	3 Hrs.		Maximum Marks:	60
Note:	All q	uestions are compulsory. Inte	ernal choices, i	f any, are indicated. Answers	5 0
Q.1 (N	ICQs	s) should be written in full inst	tead of only a, l	o, c or d.	
Q.1	i.	In Boolean algebra, the properties?	OR operation	is performed by which	1
			(b) Commutat	ive properties	
		(c) Distributive properties	(d) All of thes	e	
	ii.	Binary number 1001 is equal	to octal number	er-	1
		(a) 13 (b) 9	(c) 10	(d) 11	
	iii.	Decimal number 7 in Gray co	ode is-		1
		(a) 1100 (b) 0101	(c) 0100	(d) 0111	
	iv.	Half-adders have a major lin	they cannot-	1	
		(a) Accept a carry bit from a	present stage		
		(b) Accept a carry bit from a	next stage		
		(c) Accept a carry bit from a	previous stage		
		(d) Accept a carry bit from the	ne following sta	ges	
	v.	Latches constructed with NC	OR and NAND	gates tend to remain in the	1
		latched condition due to which	ch configuration	i feature?	
		(a) Low input voltages	(b) Gate imped	dance	
		(c) Synchronous operation	(d) Cross coup	oling	
	vi.	In T flip flop, when $T = 1$, th	be in the	1	
		(a) Set mode	(b) Compleme		
		(c) Reset mode	(d) Store mode		
	vii.	The total capacity of a memo	ory that has 102	4 addresses and can store 8	1
		bits at each address is-	4 > 100	(1) 0100	
		(a) 2048 (b) 16384	(c) 128	(d) 8192	
	viii.	How many address lines requ		temory system?	1
		(a) 13 (b) 11	(c) 12	(d) 8	

Programme: B.Tech./

B.Sc.(CS)

	ix.	Which logic has higher speed among all the logic families?				
		(a) DTL (b) RTL (c) TTL (d) ECL				
	X.	A TTL circuit acts as a current sink in the-	1			
		(a) High state (b) Low state (c) High impedance state (d) Ideal state				
Q.2	i.	Convert the decimal number 250.5 to Base 7.				
	ii.	Convert the following in other canonical form:				
		(a) $F(A,B,C) = \sum (0,2,6,7)$ (b) $F(W,X,Y,Z) = \prod (0,1,2,3,4,6,12)$				
	iii.	Reduce the following function using K-map technique-	5			
OB		$F(A, B, C, D) = \Pi(0, 3, 4, 7, 8, 10, 12, 14) + d(2, 6).$				
OR	iv.	Reduce the following using tabulation method-	5			
		F=m2+m3+m4+m6+m7+m9+m11+m13.				
Q.3		Change 41				
Q.5	i.	Show that a positive logic AND gate is a negative-logic OR gate and	3			
	ii.	Vice versa. Design full addressive it at the second secon				
	11.	Design full adder circuit on the basis of following- (a) Circuit diagram (b) Truth table	7			
		(a) Circuit diagram (b) Truth table (c) Characteristic equation				
OR	iii.	Define multiplexer. Implement the Boolean function using 8:1 mux.				
		F (A, B, C, D) = A'BD'+ACD+B'CD+A'C'D.	7			
		T (A, B, C, B) A BD TACDTB CD+A C D.				
Q.4	i.	Define flip-flop. Write down its applications.	•			
	ii.	Explain race around condition with neat diagram.	2 3			
	iii.	Draw the circuit diagram of JK flip flop and explain its operation using	5			
	1	truth table.	3			
OR	iv		5			
OR	iv		5			
OR	iv	Design an asynchronous MOD 10 up counter with neat diagram & truth table.				
OR Q.5		Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between				
		Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between RAM & ROM.				
		Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between RAM & ROM. Write notes on any two of the following:				
Q.5	i. ii.	Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between RAM & ROM. Write notes on any two of the following: (a) EPROM (b) PAL (c) SRAM	3			
	i. ii.	Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between RAM & ROM. Write notes on any two of the following: (a) EPROM (b) PAL (c) SRAM A combinational circuit is defined by the functions.	3			
Q.5	i. ii.	Design an asynchronous MOD 10 up counter with neat diagram & truth table. State the classification of memories. Write down differences between RAM & ROM. Write notes on any two of the following: (a) EPROM (b) PAL (c) SRAM	3 7			

[3]

Q.6		Attempt any two:	
	i.	Write down following specification for logic families	
		(a) Propagation delay (b) Figure of merit (c) Fan out	
	ii.	State five characteristic of TTL logic.	3
	iii.	Write note on CMOS, NMOS, PMOS.	5
